## STUDY PREPARATION AND CHARACTERIZATION OF Cd (S0,5 Te0,5) SEMICONDUCTOR FOR SOLAR CELL Ariswan, Warsono, Rita Prasetyowati Abstract

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## **ABSTRACT**

This study aims to determine the crystal structure and lattice parameters of massif  $Cd(S_{0.5}Te_{0.5})$  results of preparation with Bridgman technique, to determine the surface morphology and chemical composition of massif  $Cd(S_{0.5}Te_{0.5})$  results of preparation with Bridgman technique. This study also aims to determine the crystal structure and lattice parameters of  $Cd(S_{0.5}Te_{0.5})$  thin film as a result of preparation with vacuum evaporation technique, to determine the surface morphology and chemical composition of  $Cd(S_{0.5}Te_{0.5})$  thin film as a result of preparation with vacuum evaporation techniques. , knowing the resistance of thin film  $Cd(S_{0.5}Te_{0.5})$  as a result of preparation with vacuum evaporation technique, and knowing the band gap energy of  $Cd(S_{0.5}Te_{0.5})$  thin film prepared by vacuum evaporation technique.

The research carried out includes two stages, namely the preparation stage and the characterization stage. The preparation stage consisted of growing massif  $Cd(S_{0.5}Te_{0.5})$  by the Bridgman method and the growth of a thin layer of  $Cd(S_{0.5}Te_{0.5})$  with vacuum evaporation technique. Characterization of XRD (X-Ray Diffraction) was carried out to determine the massive crystal structure and thin layer of  $Cd(S_{0.5}Te_{0.5})$  SEM (Scanning Electron Microscopy) characterization was carried out to determine the surface morphology of the massif and thin layers, while the characterization of EDS (Energy Dispersive Spectroscopy) was carried out to determine the chemical composition of the mass and thin layers. Characterization using a four-point probe was carried out to determine the resistance of the thin film  $Cd(S_{0.5}Te_{0.5})$ . Characterization with UV-Visible Spectrophotometer was carried out to determine the energy gap of the  $Cd(S_{0.5}Te_{0.5})$  thin film.

The XRD characterization results show that the Cd massif (S0,5 Te0,5) formed has a hexagonal structure, with a crystal lattice parameter in sample 1 that is  $a = 4,550 \text{ A}^{\circ}$ ;  $c = 7,902 \text{ A}^{\circ}$ , for sample 2 that is  $a = 4,538 \text{ A}^{\circ}$ ;  $c = 7,944 \text{ A}^{\circ}$ , and for sample 3 is  $a = 4,533 \text{ A}^{\circ}$ ;  $c = 7,902 \text{ A}^{\circ}$ . SEM characterization results show that the surface morphology of Cd massif (S0,5 Te0,5) is quite homogeneous, with the average grain size in sample 1 that is  $x = 10,584 \pm 0,176$  micron and  $y = 10,115 \pm 0,982$  micron, whereas in sample 2 that is  $x = 9,292 \pm 0,005$  micron and  $y = 8,297 \pm 0,105$  micron. The EDS characterization results show that the Cd: S: Te massif Cd (S0.5 Te0.5) ratio in sample 1 is 1: 0.3: 0.6, and in sample 2 is 1: 0.2: 0.8.

Kata Kunci: Kevwords: Cd (S0.5Te0.5), massif, thin film, solar cell